



### **600V N-Channel Super Junction MOSFET**

Voltage

600 V

Current

15 A

#### **Features**

- $R_{DS(ON)}$ ,  $V_{GS}@10V$ ,  $I_D@6.5A<0.29\Omega$
- Fast switching speed
- Low on-resistance
- Low Noise
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

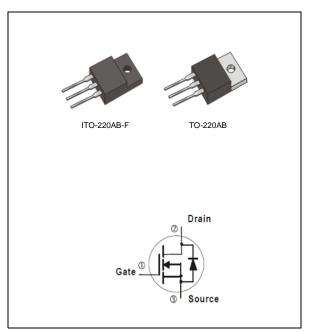
### **Mechanical Data**

• Case: TO-220AB, ITO-220AB-F Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• TO-220AB Approx. Weight: 0.067 ounces, 1.89 grams

• ITO-220AB-F Approx. Weight: 0.068 ounces, 2 grams



## Maximum Ratings and Thermal Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER		SYMBOL	TO-220AB	ITO-220AB-F	UNITS
Drain-Source Voltage		V <sub>DS</sub>	600		V
Gate-Source Voltage		$V_{GS}$	<u>+</u> 20		
Continuous Drain Current (Note 4)	T <sub>C</sub> =25°C		15		A
	T <sub>C</sub> =100°C	l <sub>D</sub>	10		
Pulsed Drain Current (Note 1)		I <sub>DM</sub>	30		7
Power Dissipation	T <sub>C</sub> =25°C	P <sub>D</sub>	184	60	10/
	T <sub>C</sub> =100°C		74	24	W
Continuous Drain Current (Note 4)	T <sub>A</sub> =25°C		1.7		А
	T <sub>A</sub> =70°C	l <sub>D</sub>	1.4		
Power Dissipation	T <sub>A</sub> =25°C	P <sub>D</sub>	2	1.04	147
	T <sub>A</sub> =70°C		1.3	0.9	W
Single Pulse Avalanche Energy (Note 5)		E <sub>AS</sub>	288		mJ
Operating Junction and		$T_J, T_STG$	55, 450		°C
Storage Temperature Range			-55~150		
(Note 4.5)		$R_{ heta JC}$	0.68	2.08	°C/W
Typical Thermal Resistance (Note 4,5)		$R_{ heta JA}$	62.5	120	

Limited only By Maximum Junction Temperature





## **Electrical Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =250uA	600	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=250uA$	2	3	4	
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =6.5A	-	0.25	0.29	Ω
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =600V, V <sub>GS</sub> =0V	-	-	1	uA
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = <u>+</u> 20V, V <sub>DS</sub> =0V	-	-	<u>+</u> 100	nA
Diode Forward Voltage	$V_{SD}$	I <sub>S</sub> =15A, V <sub>GS</sub> =0V	-	0.95	1.5	V
Transconductance	Grs	VDS=10V, ID=7.5A	-	8	-	S
Dynamic (Note 7)						
Total Gate Charge	$Q_{g}$	\/ 200\/ I 45A	-	40	-	nC
Gate-Source Charge	$Q_gs$	$V_{DS}$ =300V, $I_{D}$ =15A, $V_{GS}$ =10V (Note 2,3)	-	6.5	-	
Gate-Drain Charge	$Q_{gd}$	V <sub>GS</sub> =10V	-	21	-	
Gate Input Resistance	$R_{g}$	F = 1MHz	-	7.3	-	Ω
Input Capacitance	Ciss	\/ OF\/ \/ O\/	-	1013	-	pF
Output Capacitance	Coss	V <sub>DS</sub> =25V, V <sub>GS</sub> =0V, f=1MHZ	-	674	-	
Reverse Transfer Capacitance	Crss	I=IIVIDZ	-	91	-	
Turn-On Delay Time	td <sub>(on)</sub>	\/ 000\/ L 7.5A	-	15	-	
Turn-On Rise Time	t <sub>r</sub>	$V_{DD}=300V, I_{D}=7.5A,$ $R_{G}=10\Omega$ (Note 2,3)	-	28	-	
Turn-Off Delay Time	td <sub>(off)</sub>	$R_{G}=10\Omega$	-	109	-	
Turn-Off Fall Time	t <sub>f</sub>		-	29	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I <sub>S</sub>		-	-	15	
Maximum Pulsed Drain-Source Diode Forward Current	I <sub>SM</sub>		-	-	30	A
Reverse Recovery Time	trr	V <sub>GS</sub> =0V, I <sub>S</sub> =15A	-	441	-	ns
Reverse Recovery Charge NOTES:	Qrr	dI <sub>F</sub> / dt=100A/us (Note 2)	-	7.2	-	uC

#### NOTES:

- 1. Pulse width<300us, Duty cycle<2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Repetitive rating, pulse width limited by junction temperature  $T_{J(MAX)}$ =150°C. Ratings are based on low frequency and duty cycles to keep initial  $T_J$  =25°C.
- 4. The maximum current rating is package limited.
- 5. TO-252AA and TO-251AA mounted on a 1 inch2 with 2oz.square pad of copper.
- 6. L=100mH,  $I_{AS}$ =2.4A,  $V_{DD}$ =50V,  $R_{G}$ =25 ohm, Starting  $T_{J}$ =25°C.
- 7. Guaranteed by design, not subject to production testing.





### **TYPICAL CHARACTERISTIC CURVES**

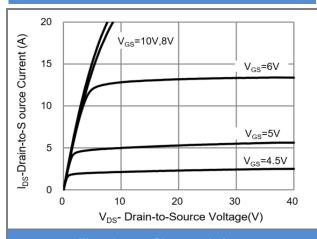
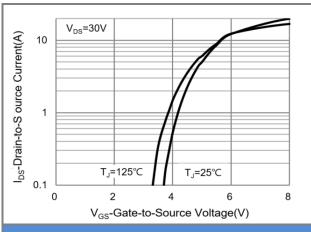


Fig.1 Output Characteristics



**Fig.2 Transfer Characteristics** 

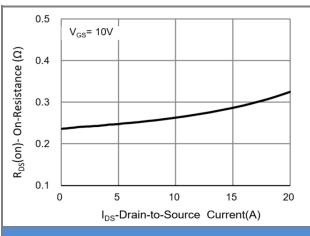


Fig.3 On-Resistance vs. Drain Current

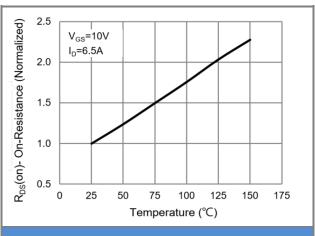


Fig.4 On-Resistance vs. Junction Temperature

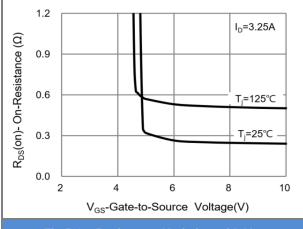


Fig.5 On-Resistance Variation with V<sub>GS</sub>

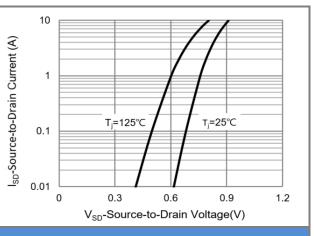


Fig.6 Source-Drain Diode Forward Voltage





#### **TYPICAL CHARACTERISTIC CURVES**

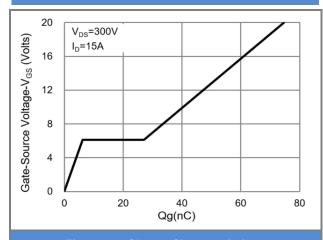


Fig.7 Gate-Charge Characteristics

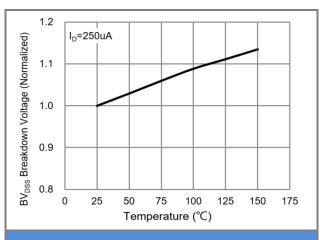


Fig.8 Breakdown Voltage Variation vs. Temperature

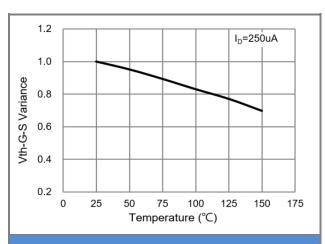


Fig.9 Threshold Voltage Variation with Temperature

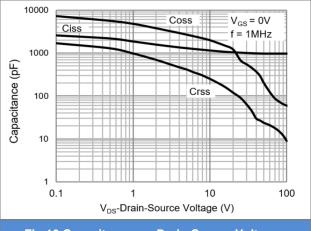


Fig.10 Capacitance vs. Drain-Source Voltage

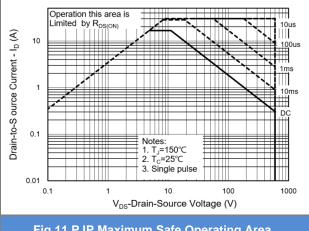


Fig.11 PJP Maximum Safe Operating Area

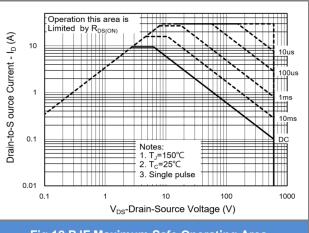
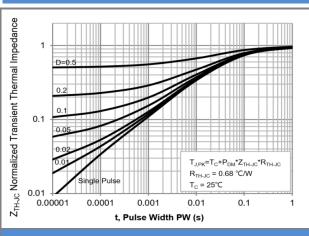


Fig.12 PJF Maximum Safe Operating Area

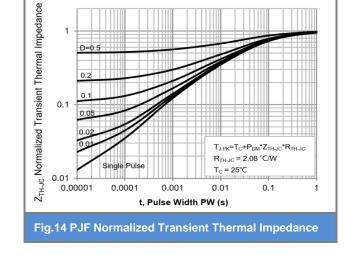


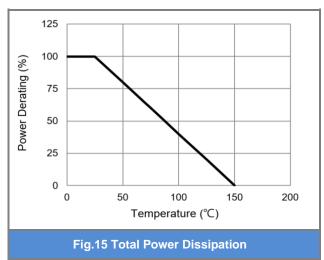


### **TYPICAL CHARACTERISTIC CURVES**



**Fig.13 PJP Normalized Transient Thermal Impedance** 

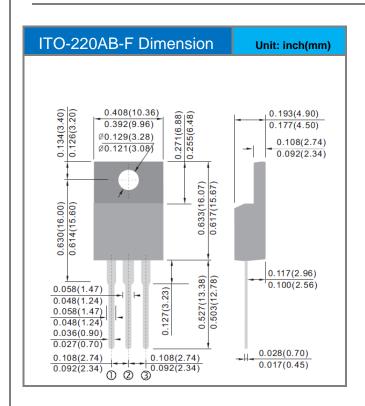


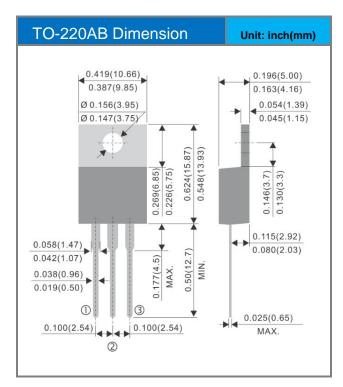






### **Packaging Information**









## **Part No Packing Code Version**

Part No Packing Code	Package Type	Packing Type Marking		Version
PJP60R290E_T0_00001	TO-220AB	50pcs / Tube	60R290E	Halogen free
PJF60R290E_T0_00001	ITO-220AB-F	50pcs / Tube	60R290E	Halogen free





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